TOSHIBA Transistor Silicon NPN Triple Diffused Type

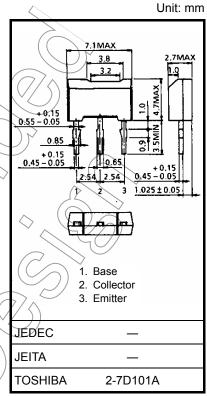
2SC6040

High-Speed and High-Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

- High-speed switching: $t_f = 0.2 \mu s \text{ (max) (IC} = 0.3 \text{ A)}$
- High breakdown voltage: $V_{CES} = 800 \text{ V}$, $V_{CEO} = 410 \text{ V}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	800	$(\checkmark \checkmark)$
Collector-emitter voltage		V _{CES}	800	*
Collector-emitter voltage		V _{CEO}	410	V
Emitter-base voltage		V _{EBO}	8	> v
Collector current	DC	IC	1.0	Α
	Pulse	ICP	2.0	A .
Base current		I _B	0.5	//A
Collector power dissipation	Ta = 25°C	Po	P _C 1.0	
Junction temperature		T	150	°C
Storage temperature range		((T _{stg}))	-55 to 150	//°c



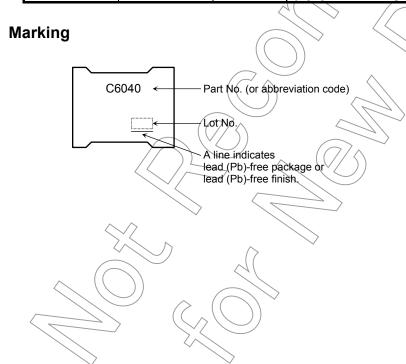
Weight: 0.2 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

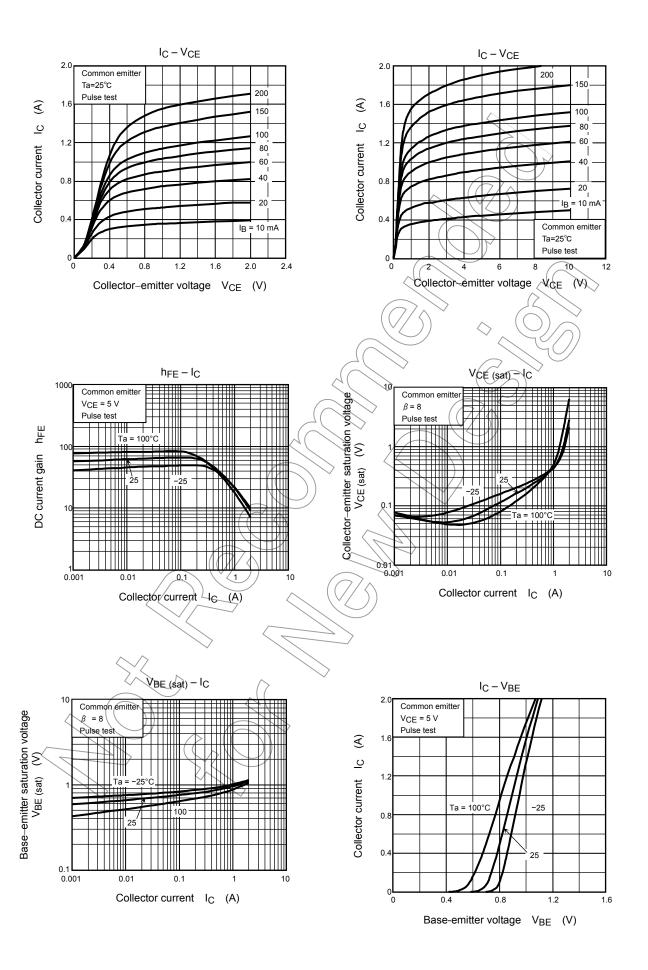
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

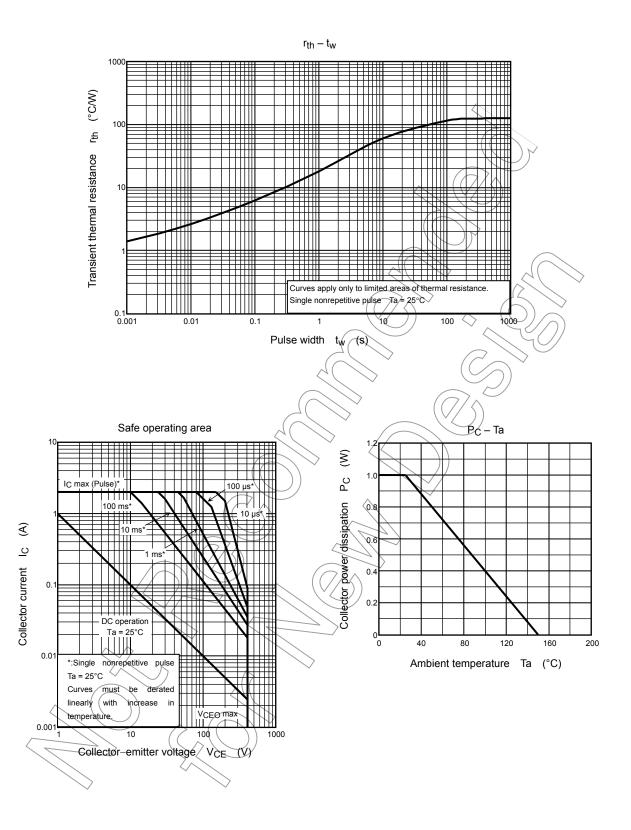
Chara	acteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I _{CBO}	V _{CB} = 800 V, I _E = 0	_	_	100	μΑ
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	100	μΑ
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _B = 0	800	_	-	٧
Collector-emitter	breakdown voltage	voltage $V_{(BR) CEO}$ $I_C = 10 \text{ mA}, I_B = 0$		410	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA 50) >-	_	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.1 A	60	_	120	
		h _{FE} (3)	V _{CE} = 5 V, I _C = 0.2 A	50	_	_	
Collector emitter saturation voltage V _{CE} (sat		V _{CE} (sat)	I _C = 0.8 A, I _B = 0.1 A	_	_	1.0	V
Base-emitter saturation voltage V _{BE (s}		V _{BE} (sat)	I _C = 0.8 A, I _B = 0.1 A	^ —	_	1.3	V
Switching time S	Rise time	t _r	20 μs	_		0.5	
	Storage time	t _{stg}	INPUT OUT-			4.0	μs
	Fall time	t _f	I _{B1} = 0.1 A, -I _{B2} = 50 mA DUTY CYCLE ≥ 1%	2)	_	0.2	



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